UTC MMBT9015 PNP EPITAXIAL SILICON TRANSISTOR

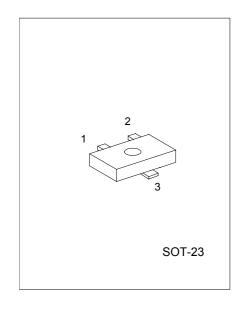
PRE-AMPLIFIER, LOW LEVEL & **LOW NOISE**

FEATURES

- *High total power dissipation. (450mW)
- *Excellent hFE linearity.
- *Complementary to UTC MMBT9014

MARKING





1: EMITTER 2: BASE 3: COLLECTOR

ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATING	UNIT
Collector-base voltage	Vсво	-50	V
Collector-emitter voltage	VCEO	-45	V
Emitter-base voltage	VEBO	-5	V
Collector current	lc	-100	mA
Collector dissipation	Pc	225	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 ~ + 150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

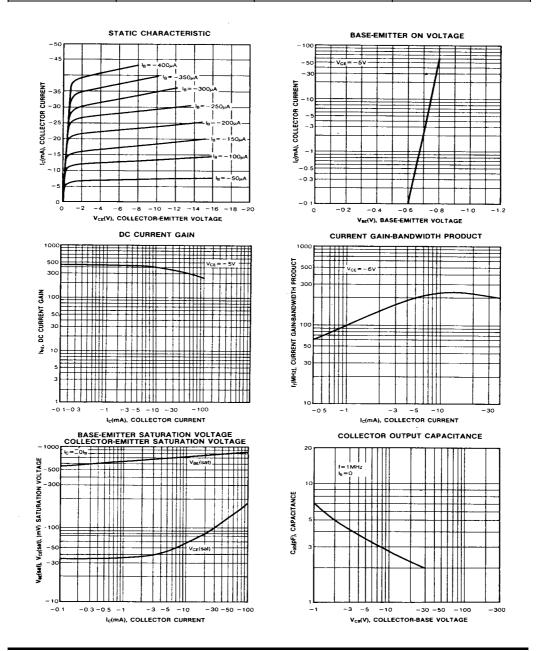
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	ВУсво	Ic=-100μA, IE=0	-50			V
Collector-emitter breakdown voltage	BVCEO	Ic=-1mA, IB=0	-45			V
Emitter-base breakdown voltage	BVEBO	IE=-100μA, Ic=0	-5			V
Collector cutoff current	Ісво	Vcb=-50V, IE=0			-50	nA
Emitter cutoff current	lево	VEB=-5V, IC=0			-100	nA
DC current gain	hFE	Vce=-5V, Ic=-1mA	60	200	600	
Collector-emitter saturation voltage	Vce(sat)	Ic=-100mA, IB=-5mA		-0.2	-0.7	V
Base-emitter saturation voltage	V _{BE} (sat)	lc=-100mA, IB=-5mA		-0.82	-1.0	V
Base-emitter on voltage	VBE(on)	Vce=-5V, Ic=-2mA	-0.6	-0.65	-0.75	V
Output Capacitance	Cob	Vcb=-10V, IE=0, f=1MHz		4.5	7.0	pF
Current gain-Bandwidth Porduct	fT	Vce=-5V, lc=-10mA	100	190		MHz
Noise Figure	NF	Vce=-5V, Ic=-0.2mA		0.7	10	dB
		f=1KHz, Rs=1KΩ				

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CLASSIFICATION OF hFE

RANK	Α	В	С
RANGE	60-150	100-300	200-600



UTC

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UTC MMBT9015 PNP EPITAXIAL SILICON TRANSISTOR

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